

# **DSA 20 C 100 PN**

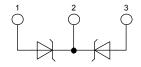
advanced

## **Schottky Diode**

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

Part number

**DSA 20 C 100 PN** 

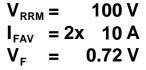


#### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters





Backside: isolated

#### Package:

**F1** E72873

- Housing: TO-220FP
- Industry standard outline
- Plastic overmolded tab for electrical isolation
- Epoxy meets UL 94V-0
- RoHS compliant

#### Ratings

Symbol	Definition	Conditions		min.	typ.	max.	Unit
$V_{RRM}$	max. repetitive reverse voltage		T <sub>VJ</sub> = 25°C			100	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 100 V	$T_{VJ} = 25^{\circ}C$			0.2	μΑ
		$V_R = 100 V$	$T_{VJ} = 125^{\circ}C$			2	mΑ
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 A	$T_{VJ} = 25^{\circ}C$			0.90	V
		$I_F = 20 A$				1.50	V
		I <sub>F</sub> = 10 A	T <sub>VJ</sub> = 125°C			0.72	V
		$I_F = 20 A$				0.88	V
I <sub>FAV</sub>	average forward current	rectangular, d = 0.5	$T_c = 145$ °C			10	Α
V <sub>F0</sub>	threshold voltage	alanda Cara and a	T <sub>vJ</sub> = 175°C			0.46	V
r <sub>F</sub>	slope resistance	alculation only				17	mΩ
$R_{thJC}$	thermal resistance junction to case					4.50	K/W
T <sub>vJ</sub>	virtual junction temperature			-55		175	°C
P <sub>tot</sub>	total power dissipation		$T_{c} = 25^{\circ}C$			35	W
I <sub>FSM</sub>	max. forward surge current	t = 10 ms (50 Hz), sine	$T_{VJ} = 45^{\circ}C$			220	Α
CJ	junction capacitance	$V_R = \text{tbd V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		tbd		pF

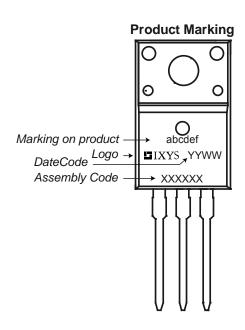




advanced

		Ratings				
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I <sub>RMS</sub>	RMS current	per pin 1)			35	Α
R <sub>thCH</sub>	thermal resistance case to heat	sink		0.50		K/W
T <sub>stg</sub>	storage temperature		-55		150	°C
Weight				2		g
M <sub>D</sub>	mounting torque		0.4		0.8	Nm
F <sub>c</sub>	mounting force with clip		20		60	N

<sup>1)</sup> I<sub>RMS</sub> is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip. In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.



#### Part number

D = Diode

S = Schottky Diode

A = low VF

20 = Current Rating [A]

C = Common Cathode 100 = Reverse Voltage [V]

PN = TO-220ACFP (3)

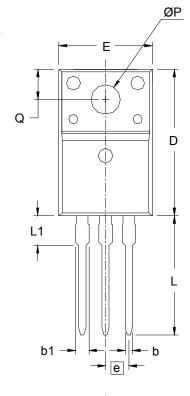
Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Code Key
Standard	DSA 20 C 100 PN	DSA20C100PN	Tube	50	503516

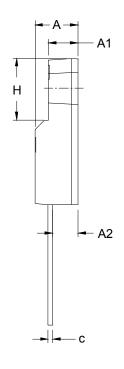
Similar Part	Package	Voltage class
DSA20C100PB	TO-220	100
DSA20C60PN	TO-220FP	60
DSSK20-0045AM	TO-220	45
DSSK20-015A	TO-220	150



#### advanced







SYM	INCHES		MILLIMETERS		
2114	MIN	MAX	MIN	MAX	
Α	.177	.193	4.50	4.90	
A1	.092	.108	2.34	2.74	
A2	.101	.117	2.56	2.96	
b	.028	.035	0.70	0.90	
b1	.050	.058	1.27	1.47	
С	.018	.024	0.45	0.60	
D	.617	.633	15.67	16.07	
E	.392	.408	9.96	10.36	
е	.100 BSC		2.54 BSC		
Н	.255	.271	6.48	6.88	
L	.499	.523	12.68	13.28	
L1	.119	.135	3.03	3.43	
ØP	.121	.129	3.08	3.28	
Q	.126	.134	3.20	3.40	

_				_
1	пт		mm	
$\vdash$		щ		
1		i		
l		!		
		i_		